



Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a TO92 plastic package intended for use in applications requiring enhanced noise immunity and direct interfacing to logic ICs and low power gate drivers.

2. Features and benefits

- Direct interfacing to logic level ICs
- Enhanced current surge capability
- Enhanced noise immunity
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate in four quadrants

3. Applications

- General purpose low power motor control
- Home appliances
- Industrial process control
- Low power AC Fan controllers

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
		Conditions			Тур	IVIAX	Unit
Absolute	maximum rating	1					
V _{DRM}	repetitive peak off-state voltage			-	-	600	V
I _{T(RMS)}	RMS on-state current	Fig. 1; Fig. 2; Fig. 3		-	-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>		-	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms		-	-	13.8	А
Tj	junction temperature			-	-	125	°C
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 7</u>		0.2	-	3	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$		0.2	-	3	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u>		0.2	-	3	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>		0.2	-	5	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>		-	-	7	mA
V _T	on-state voltage	I _τ = 1.4 A; T _i = 25 °C; <u>Fig. 10</u>		-	1.3	1.6	V

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 110 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12		80	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	V_{D} = 400 V; T _j = 110 °C; dI _{com} /dt = 0.44 A/ms; gate open circuit		0.5	-	-	V/µs

5. Pinning information

Table 2. P	Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol					
1	T2	main terminal 2		Ν					
2	G	gate	Li L						
3	T1	main terminal 1) TO-92 (SOT54)	sym051					

6. Ordering information

Table 3. Ordering information									
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date			
Z0103MA0	TO92	Z0103MA0,412	Bulk	1000	SOT54	14-Nov-2013			
Z0103MA0	TO92	Z0103MA0,116	Reel	2000	SOT54 wide pitch	14-Nov-2013			

7. Marking

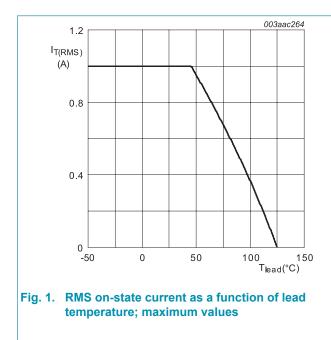
Table 4. Marking codes	
Type number	Marking codes
Z0103MA0	103MA0

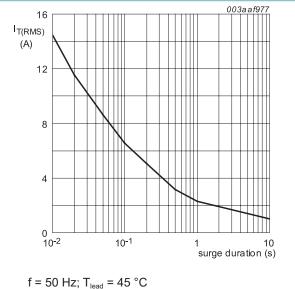
8. Limiting values

Table 5. Limiting values

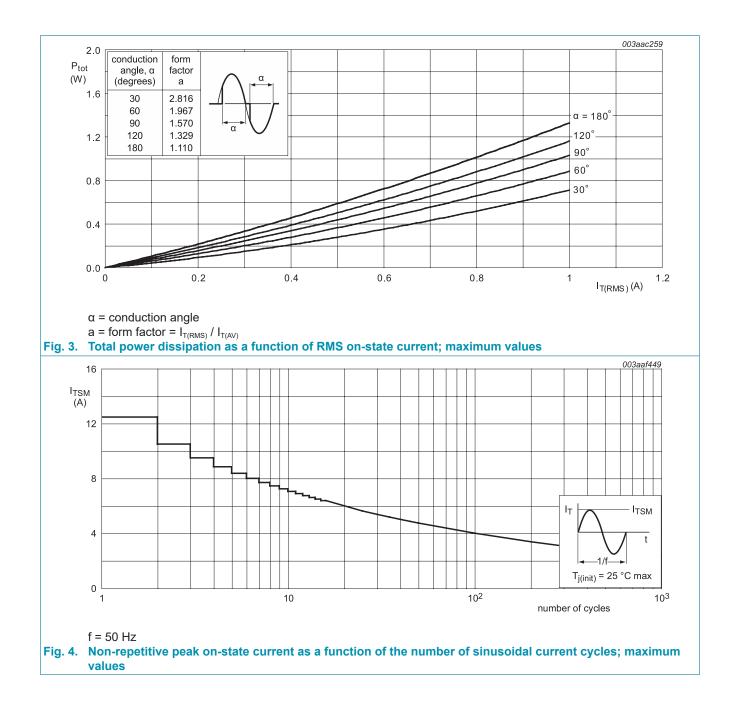
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{lead} ≤ 45 °C; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u>	-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; Fig. 4; Fig. 5	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	13.8	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.78	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 20 mA; T2+ G+	-	50	A/µs
		I _G = 20 mA; T2+ G-	-	50	A/µs
		I _G = 20 mA; T2- G-	-	50	A/µs
		I _G = 20 mA; T2- G+	-	20	A/µs
I _{GM}	peak gate current		-	1	А
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	125	°C



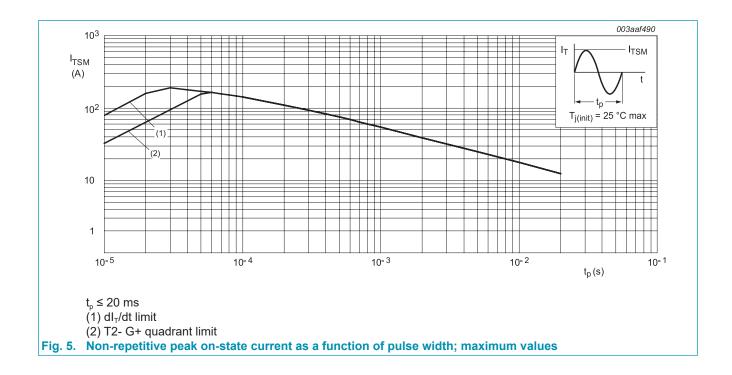






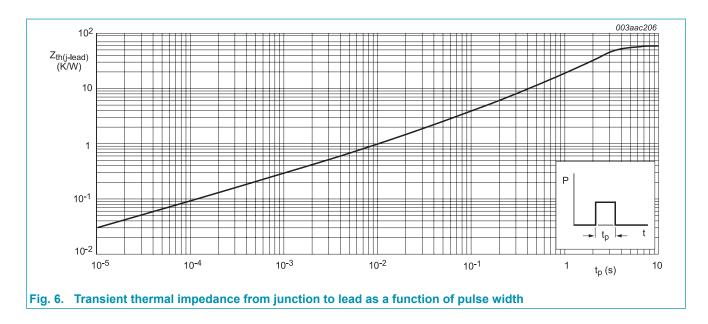
4Q Triac

Z0103MA0



9. Thermal characteristics

Table 6. Th	ble 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle; <u>Fig. 6</u>		-	-	60	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	full cycle; printed circuit board: lead length = 4 mm		-	150	-	K/W	

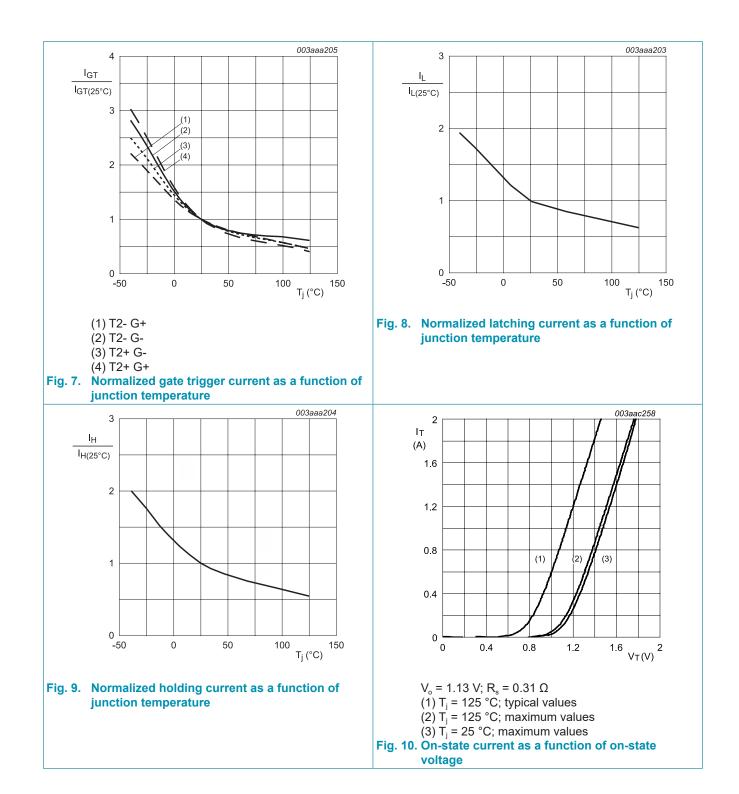


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	· · · · · · · · · · · · · · · · · · ·				
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	0.2	-	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	0.2	-	3	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	0.2	-	3	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 7	0.2	-	5	mA
ΙL	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 8	-	-	7	mA
		$V_{\rm D}$ = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 8	-	-	20	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	7	mA
		$V_{\rm D}$ = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; Fig. 8	-	-	7	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	7	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.6	V
V _{gt}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	-	1	V
		$V_{\rm D}$ = 600 V; I _T = 0.1 A; T _j = 125 °C	0.2	-	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	-	0.5	mA
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 110 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	80	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 110 \text{ °C}; \text{ dI}_{com}/\text{dt} = 0.44$ A/ms; gate open circuit	0.5	-	-	V/µs

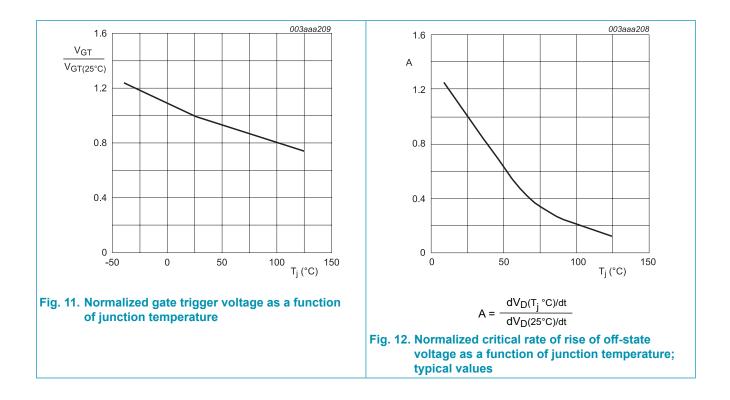
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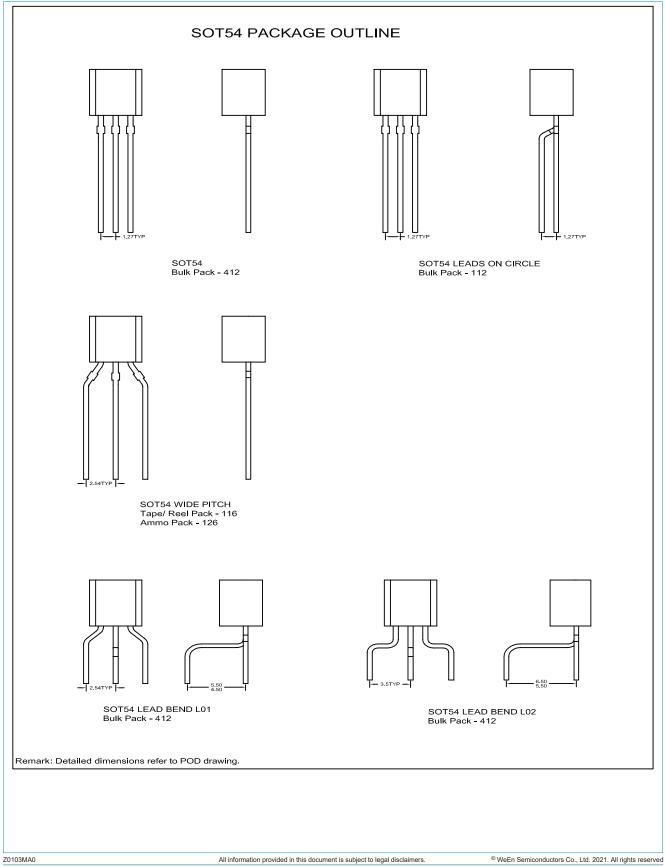


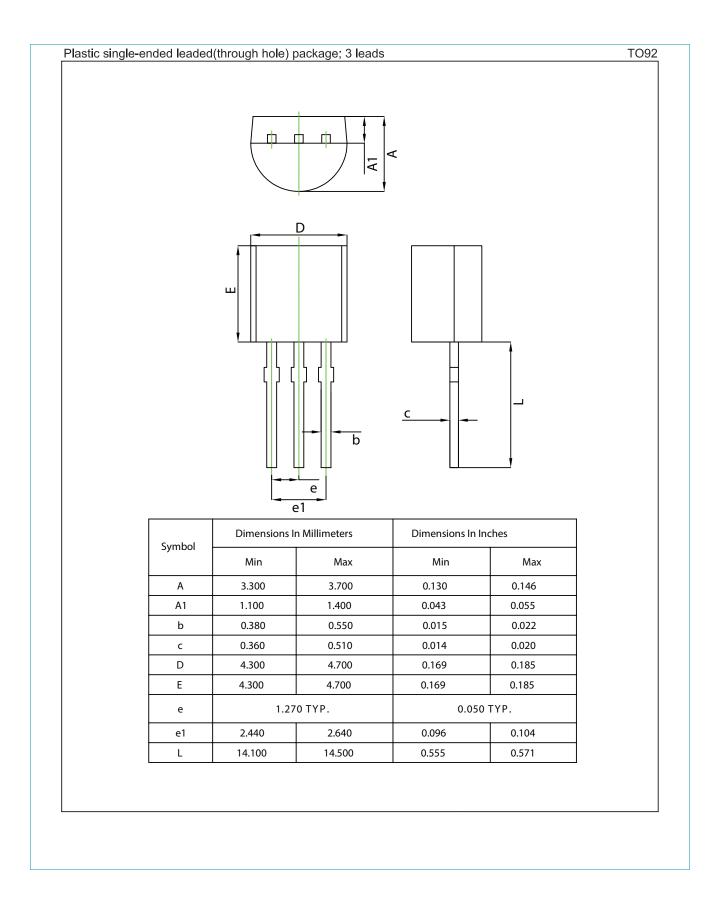
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11. Package outline





12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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